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# Anthryl-Substituted TrialkyIdisilene Showing Distinct Intramolecular Charge-Transfer Transition 

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Although many stable disilenes hitherto reported ${ }^{1}$ have organic $\pi$-electron systems as bulky sterically protecting substituents, very few studies have been directed toward understanding the characteristics of the electronic communication including conjugation and intramolecular charge transfer (ICT) interaction between a $\mathrm{Si}=\mathrm{Si}$ double bond $(\pi \mathrm{Si})$ and a carbon $\pi$-electron system $(\pi \mathrm{C}) .^{2}$ All known disilenes bound to $\pi \mathrm{C}$ systems have multiple $\pi \mathrm{Si}-\pi \mathrm{C}$ interactions and, hence, are not suitable for defining the nature of a single $\pi \mathrm{Si}-\pi \mathrm{C}$ interaction. ${ }^{2}$ We would like to report the synthesis and properties of a series of trialkyldisilenes with single polycyclic aromatic substituents $\mathbf{1}-\mathbf{3}$. ${ }^{3}$ These disilenes allowed elucidation of the unprecedented ICT interaction between $\pi \mathrm{Si}$ and $\pi \mathrm{C}$ systems, while no appreciable $\pi \mathrm{Si}-\pi \mathrm{C}$ conjugation is expected because of their mutually perpendicular arrangement. Anthryl-substituted disilene $\mathbf{3}$ having a low-lying $\pi^{*}$ (aryl) LUMO showed a distinct ICT absorption band due to the charge transfer from a $\pi \mathrm{Si}$ donor to a $\pi \mathrm{C}$ acceptor.


To synthesize disilenes $\mathbf{1}-\mathbf{3}$, new disilenide $\mathbf{4}$ was prepared by reduction of trichlorodisilane $\mathbf{6}$, which was obtained from isolable dialkylsilylene $5^{4}$ and $t$ - $\mathrm{BuSiCl}_{3},{ }^{5}$ with excess $\mathrm{KC}_{8}$ in THF (Scheme 1). ${ }^{6,7}$ While stable disilenides have been extensively investigated by Scheschkewitz ${ }^{8}$ and Sekiguchi et al., ${ }^{9} \mathbf{4}$ is unique in that it is a trialkyldisilenide without any $\pi$ substituents.

## Scheme 1



Disilenes $\mathbf{1 - 3}$ were synthesized by reactions of $\mathbf{4}$ with the corresponding aryl bromides. ${ }^{6}$ Recrystallization from diethyl ether at $-30^{\circ} \mathrm{C}$ gave air-sensitive colored crystals of disilenes: 1-naphthyldisilene $\mathbf{1}(10 \%$, yellow), 9 -phenanthryldisilene $2(20 \%$, yellow), and 9 -anthryldisilene 3 ( $41 \%$, blue-purple). ${ }^{10}$

Molecular structures of disilenes $\mathbf{1 - 3}$ determined by X-ray analysis are shown in Figure 1. ${ }^{6}$ All disilenes have a trans-bent geometry around the $\mathrm{Si}=\mathrm{Si}$ double bond with bent angles ${ }^{11}$ of $23.8^{\circ}$ and $12.2^{\circ}, 26.7^{\circ}$ and $12.9^{\circ}$, and $11.4^{\circ}$ and $6.9^{\circ}$ around Si 1 and Si 2 atoms of $\mathbf{1}, \mathbf{2}$, and $\mathbf{3}$, respectively. The $\mathrm{Si}=\mathrm{Si}$ bond lengths

[^0][2.1943(14), 2.209(2), and 2.1754(12) $\AA$ for $1-3$ ] are in the region of those for typical acyclic disilenes. ${ }^{1}$ It should be noted that disilene $\pi(\pi \mathrm{Si})$ and aromatic $\pi(\pi \mathrm{C})$ systems are almost perpendicular to each other with a dihedral angle $\delta^{11}$ of $83^{\circ}, 80^{\circ}$, and $88^{\circ}$ for $\mathbf{1 , 2}$, and 3.


Figure 1. Molecular structures of $\mathbf{1}$ (left), $\mathbf{2}$ (middle), and $\mathbf{3}$ (right). Thermal ellipsoids are shown at the $50 \%$ probability level. Hydrogen atoms are omitted for clarity.

Disilenes $\mathbf{1}$ and 2 in 3-methylpentane show similar three absorption bands (bands I-III) in the UV-vis region as typically shown for $\mathbf{1}$ in Figure 2a. ${ }^{12}$ Band I having fine structures is observed at 287 and 304 nm for $\mathbf{1}$ and 2, respectively, and assignable to the ${ }^{1} L_{\mathrm{a}}$ band of the corresponding $\pi \mathrm{C}$ systems because the reported ${ }^{1} L_{\mathrm{a}}$ band maxima of 1-(pentamethyldisilanyl)naphthalene and 9 -(pentamethyldisilanyl)phenanthrene are 287 and $302 \mathrm{~nm} .{ }^{13}$ The other two major bands of $\mathbf{1}$ and $\mathbf{2}$ (bands II and III) are very similar to each other, and hence, these bands are assigned to the transition originating from the common disilene moiety; $\lambda_{\max } / \mathrm{nm} 342$ and 376 for $\mathbf{1}$ and 343 and 378 for $\mathbf{2} .^{14}$ An apparent spectral feature of anthryldisilene $\mathbf{3}$ is very different from those of $\mathbf{1}$ and $\mathbf{2}$ as shown in Figure 2b, but the intense structured band between 320 and 450 nm with an $\varepsilon$ of $19.7 \times 10^{3}$ is regarded as band I overlapped with bands II and III, because the ${ }^{1} L_{\mathrm{a}}$ band of 9 -(pentamethyldisilany1)anthracene appears at 373 nm with an $\varepsilon$ of $8.42 \times 10^{3} .{ }^{13}$ All these spectral features are in good accord with the picture that the $\pi \mathrm{Si}$ and $\pi \mathrm{C}$ systems are independent of each other and there is no significant conjugation between the two $\pi$ systems, as expected by the mutually perpendicular arrangement of the two $\pi$ systems.

A noticeable spectral feature of $\mathbf{3}$ is the presence of a weak but distinct absorption band at $525 \mathrm{~nm}(\varepsilon 420)$ in 3-methylpentane (band IV), which red-shifts to $535 \mathrm{~nm}(\varepsilon 480)$ in more polar 1,2dichlorobenzene, ${ }^{15}$ suggesting the ICT nature of this band.

To elucidate the nature of the absorption bands of $\mathbf{1 - 3}$, DFT calculations at the B3LYP/6-311G(d) level ${ }^{16}$ are carried out for model compounds $\mathbf{1}^{\prime}-\mathbf{3}^{\prime}$, where $\mathrm{SiMe}_{3}$ groups in $\mathbf{1 - 3}$ are replaced by $\mathrm{SiH}_{3}$ groups. The molecular structures of disilenes $\mathbf{1 - 3}$
determined by X-ray crystallography are reproduced well in optimized structures of $\mathbf{1}^{\prime} \mathbf{- \mathbf { 3 } ^ { \prime }}$. The almost perpendicular geometry between the $\mathrm{Si}=\mathrm{Si}$ bond and aromatic $\pi$ plane in $\mathbf{1}^{\prime}-\mathbf{3}^{\prime}\left(\delta 82^{\circ}\right.$, $81^{\circ}$, and $83^{\circ}$ for $\mathbf{1}^{\prime}, \mathbf{2}^{\prime}$, and $\mathbf{3}^{\prime}$ ) supports compounds $\mathbf{1}-\mathbf{3}$ having similar perpendicular geometry even in solution. Frontier Kohn-Sham orbitals of $\mathbf{1}^{\prime}-\mathbf{3}^{\prime}$ are almost pure $\pi$ and $\pi^{*}$ orbitals of disilene and aryl moieties, and their energy levels are almost the same as those of the component $\pi \mathrm{Si}$ and $\pi \mathrm{C}$ systems, ${ }^{16}$ indicating no significant conjugative interaction between the two $\pi$ systems (Figure 3). The calculated absorption maxima and oscillator strengths of $\mathbf{1}^{\prime}-\mathbf{3}^{\prime}$ using the TD-DFT method show good qualitative agreement with those of $\mathbf{1 - 3}$ : the band positions and relative intensities for $\mathbf{1}^{\prime}$ and $\mathbf{3}^{\prime}$ are shown using vertical bars in Figure 2.


Figure 2. UV-vis spectra of (a) $\mathbf{1}$ and (b) $\mathbf{3}$ in 3-methylpentane at 298 K superimposed by the calculated band positions of $\mathbf{1}^{\prime}$ and $\mathbf{3}^{\prime}$. Selected theoretical transitions: a: $\pi($ aryl $) \rightarrow \pi^{*}($ aryl $), \mathrm{b}: \pi(\mathrm{Si}=\mathrm{Si}) \rightarrow \sigma^{*}($ ring $\mathrm{Si}-\mathrm{C})$, $\mathrm{c}: \pi(\mathrm{Si}=\mathrm{Si}) \rightarrow \pi^{*}(\mathrm{Si}=\mathrm{Si}), \mathrm{d}: \pi(\mathrm{Si}=\mathrm{Si}) \rightarrow \pi^{*}($ aryl $)$.


Figure 3. Orbital energy diagram of aryldisilenes $\mathbf{1}^{\prime}-\mathbf{3}^{\prime}$ calculated at the B3LYP/6-311++G(d,p)//B3LYP/6-311G(d) level.

Judging from the comparison between experimental and theoretical UV-vis spectra, bands I, II, and III of disilenes $\mathbf{1 - 3}$ are assignable to transitions a $\left[\pi(\operatorname{aryl}) \rightarrow \pi^{*}(\right.$ ary $\left.)\right], \mathrm{b}\left[\pi(\mathrm{Si}=\mathrm{Si}) \rightarrow \sigma^{*}(\right.$ ring $\mathrm{Si}-\mathrm{C})]$, and c $\left[\pi(\mathrm{Si}=\mathrm{Si}) \rightarrow \pi^{*}(\mathrm{Si}=\mathrm{Si})\right]$. Theoretical calculations confirm that the broad $320-450 \mathrm{~nm}$ band of $\mathbf{3}$ is due to the overlap of bands a, b, and c. The weak absorption at 525 nm of $\mathbf{3}$ (band IV) is assigned as an ICT transition from $\pi(\mathrm{Si}=\mathrm{Si})$ to $\pi^{*}$ (aryl) orbitals (transition d). Because similar $\pi \mathrm{Si} \rightarrow \pi^{*} \mathrm{C}$ ICT transition bands are predicted at 444 and 444 nm for $\mathbf{1}^{\prime}$ and $\mathbf{2}^{\prime}$, the broad tails of band III of $\mathbf{1}$ and $\mathbf{2}$ may be assigned to the ICT absorption bands. The absorption spectra of $\mathbf{1 - 3}$ suggests that a $\pi \mathrm{C}$ system having a lower-lying $\pi^{*}$ LUMO such as anthracene and longer acenes is indispensable for a distinct longer-wavelength ICT band. ${ }^{17}$

The present study offers a guideline to designing unique materials showing effective ICT interaction between a $\pi \mathrm{Si}$ donor and a $\pi \mathrm{C}$ acceptor. ${ }^{18}$

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Supporting Information Available: Experimental details for 1-4, details for the calculations of $\mathbf{1}^{\prime}-\mathbf{3}^{\prime}$ and related compounds, and X-ray crystallographic data of $\mathbf{1 - 4}$ in CIF format. This material is available free of charge via the Internet at http://pubs.acs.org.

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(6) For details of synthesis and X-ray analysis of $\mathbf{1 - 4}$, see Supporting Information.
(7) In the solid state, disilenide 4 adopts a dimeric structure with a fourmembered ring made of $\mathrm{Si}\left(\mathrm{sp}^{2}\right)-\mathrm{K}-\mathrm{Si}\left(\mathrm{sp}^{2}\right)-\mathrm{K}$ atoms, while disilenides reported by Scheschkewitz ${ }^{8}$ and Sekiguchi et al. ${ }^{9}$ are monomeric.
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(10) The reaction of $\mathbf{4}$ with bromobenzene gave a complex mixture.
(11) Bent angle is defined as the angle between the axis through the $\mathrm{Si}=\mathrm{Si}$ bond and $\mathrm{R}-\mathrm{Si}\left(\mathrm{sp}^{2}\right)-\mathrm{R}$ plane, and dihedral angle $\delta$ is defined as the angle between the two axes that bisect $\mathrm{Si}\left(\mathrm{sp}^{2}\right)-\mathrm{Si}\left(\mathrm{sp}^{2}\right)-\mathrm{C}(t-\mathrm{Bu})$ and $\mathrm{C}\left(\mathrm{sp}^{2}\right)-\mathrm{C}(\mathrm{ipso})-\mathrm{C}\left(\mathrm{sp}^{2}\right)$ angles as viewed along the $\mathrm{Si}\left(\mathrm{sp}^{2}\right)-\mathrm{C}($ aryl $)$ bond axis.
(12) See Supporting Information for details of UV—vis spectrum of 2.
(13) The $\lambda_{\max }(\varepsilon)$ of the ${ }^{1} L_{\mathrm{a}}$ of 1-naphthyl-, 9-phenanthryl-, and 9-anthrylsubstituted pentamethyldisilanes are reported to be $287 \mathrm{~nm}\left(9.94 \times 10^{3}\right)$, $302 \mathrm{~nm}\left(1.62 \times 10^{4}\right)$, and $373 \mathrm{~nm}\left(8.42 \times 10^{3}\right)$, respectively. Shizuka, H.; Sato, Y.; Ueki, Y.; Ishikawa, M.; Kumada, M. J. Chem. Soc., Faraday Trans. 1 1984, 80, 341.
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(18) Preliminarily, when band I of $\mathbf{3}$ was excited in hexane, emission from anthryl $\pi \pi^{*}$ state was observed at 415 nm with a lower quantum yield (0.14) than that for 9-anthrylpentamethyldisilane (0.73). ${ }^{13}$ Excitation of the ICT band showed no emission.

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